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Vishay Siliconix

N-Channel 100 V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|---------------------|-----------------------------------|--------------------|-----------------------|--|--|
| V _{DS} (V) | R _{DS(on)} (Ω) MAX. | I _D (A) | Q _g (TYP.) | | |
| 100 | 0.0056 at V _{GS} = 10 V | 131 | 53.5 nC | | |
| | 0.0062 at V _{GS} = 7.5 V | 129 | 33.3 110 | | |



Ordering Information:

SUM70060E-GE3 (lead (Pb)-free and halogen-free)

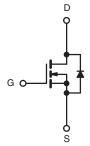
FEATURES

- ThunderFET® power MOSFET
- Maximum 175 °C junction temperature
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- · Battery management



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted) | | | | | | |
|---|-----------------------------------|-----------------|------------------|----|--|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | | | |
| Drain-Source Voltage | V _{DS} | 100 | V | | | |
| Gate-Source Voltage | V _{GS} | ± 20 | V | | | |
| Continuous Proin Current (T. – 150 °C) | T _C = 25 °C | 1 | 131 | Δ. | | |
| Continuous Drain Current (T _J = 150 °C) | T _C = 125 °C | I _D | 75 | | | |
| Pulsed Drain Current (t = 100 μs) | I _{DM} | 240 | Α | | | |
| Avalanche Current L = 0.1 mH | | I _{AS} | 50 | | | |
| Single Avalanche Energy ^a | L=0.1 IIII | E _{AS} | 125 | mJ | | |
| Maximum Power Dissipation ^a | T _C = 25 °C | В | 375 b | W | | |
| Maximum Fower Dissipation ~ | T _C = 125 °C | P _D | 125 ^b | | | |
| Operating Junction and Storage Temperature R | T _J , T _{stg} | -55 to +175 | °C | | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|-------------------|-------|---------|--|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | | |
| Junction-to-Ambient (PCB Mount) ^c | R _{thJA} | 40 | °C // / | | |
| Junction-to-Case (Drain) | R _{thJC} | 0.75 | °C/W | | |

Notes

- a. Duty cycle ≤ 1 %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR4 material).



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| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
|---------------------------------------|----------------------|--|------|--------|--------|-------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | 100 | - | - | V | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | 2 | - | 4 | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | - | - | ± 100 | nA | |
| | | V _{DS} = 100 V, V _{GS} = 0 V | - | - | 1 | μΑ | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} = 100 V, V_{GS} = 0 V, T_J = 125 °C | - | - | 100 | | |
| | | V_{DS} = 100 V, V_{GS} = 0 V, T_J = 175 °C | - | - | 2 | mA | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$ | 90 | - | - | Α | |
| Drain-Source On-State Resistance a | П | $V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ | - | 0.0046 | 0.0056 | Ω | |
| Drain-Source On-State Resistance | R _{DS(on)} | $V_{GS} = 7.5 \text{ V}, I_D = 30 \text{ A}$ | - | 0.0048 | 0.0062 | | |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = 15 \text{ V}, I_D = 30 \text{ A}$ | - | 85 | - | S | |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | | - | 3330 | - | | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 \text{ V}, V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}$ | 1 | 1395 | - | pF | |
| Reverse Transfer Capacitance | C _{rss} | | - | 95 | - | | |
| Total Gate Charge ^c | Qg | | - | 53.5 | 81 | nC | |
| Gate-Source Charge ^c | Q _{gs} | $V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ | - | 14.5 | - | | |
| Gate-Drain Charge ^c | Q_{gd} | | - | 13.2 | - | | |
| Gate Resistance | R_g | f = 1 MHz | 0.9 | 1.9 | 3.8 | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | | - | 13 | 26 | | |
| Rise Time ^c | t _r | $V_{DD} = 50 \text{ V}, R_1 = 1.67 \Omega$ | - | 22 | 44 | | |
| Turn-Off Delay Time ^c | t _{d(off)} | $I_D\cong 30$ A, $V_{GEN}=10$ V, $R_g=1~\Omega$ | - | 27 | 54 | ns ns | |
| Fall Time ^c | t _f | | - | 9 | 18 | | |
| Drain-Source Body Diode Ratings ar | nd Characteri | stics ^b (T _C = 25 °C) | | | | | |
| Pulsed Current (t = 100 μs) | I _{SM} | | - | - | 240 | Α | |
| Forward Voltage ^a | V _{SD} | I _F = 30 A, V _{GS} = 0 V | - | 0.86 | 1.4 | ٧ | |
| Reverse Recovery Time | t _{rr} | | - | 88 | 176 | ns | |
| Peak Reverse Recovery Charge | I _{RM(REC)} | $I_F = 30 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$ | - | 5 | 10 | Α | |
| Reverse Recovery Charge | Q _{rr} | | - | 0.22 | 0.44 | μC | |

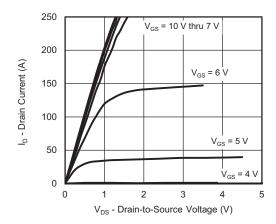
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

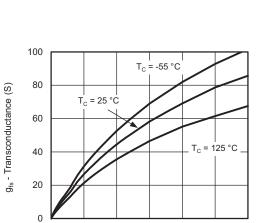
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Output Characteristics



Transconductance

15.0

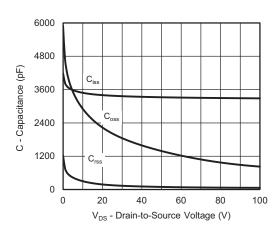
I_D - Drain Current (A)

20.0

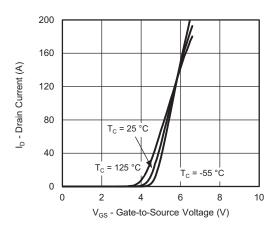
25.0

30.0

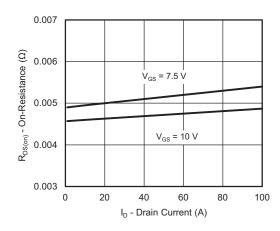
5.0



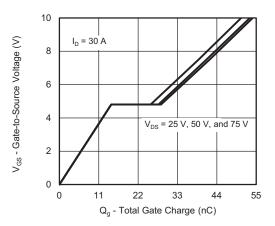
Capacitance



Transfer Characteristics



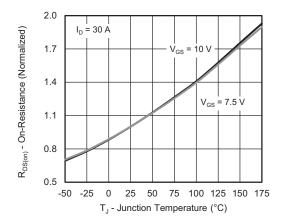
On-Resistance vs. Drain Current



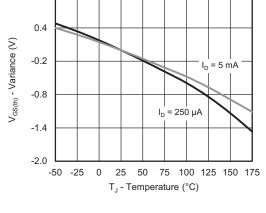
Gate Charge



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

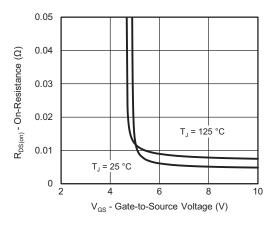


On-Resistance vs. Junction Temperature

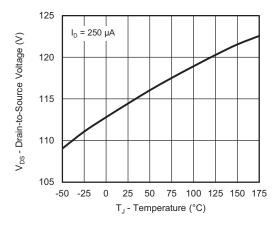


1.0

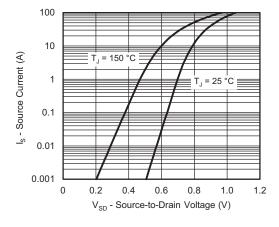
Threshold Voltage



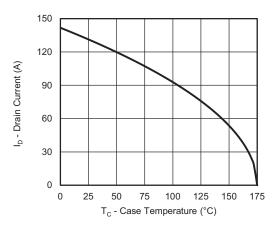
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



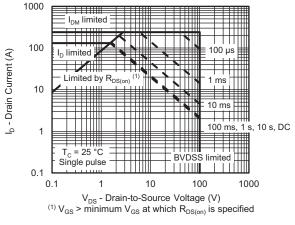
Source Drain Diode Forward Voltage

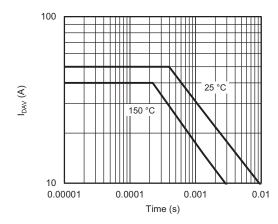


Current De-Rating



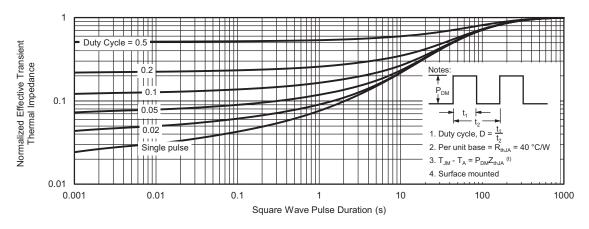
THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)





Safe Operating Area

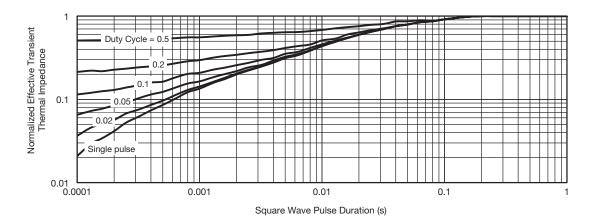
I_{DAV} vs. Time



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

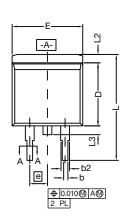
Note

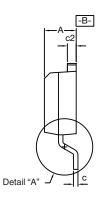
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

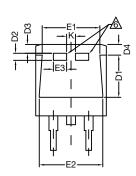
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TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



| <u> </u> | b | |
|----------|-----------------|---|
| 2 T | ਹ <i>ੀ </i> | |
| | SECTION A-4 | 1 |

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

| DIM. | | INC | HES | MILLIMETERS | | |
|---------------------------------|------------|-----------|-------|-------------|--------|--|
| | | MIN. | MAX. | MIN. | MAX. | |
| Α | | 0.160 | 0.190 | 4.064 | 4.826 | |
| | b | 0.020 | 0.039 | 0.508 | 0.990 | |
| | b1 | 0.020 | 0.035 | 0.508 | 0.889 | |
| | b2 | 0.045 | 0.055 | 1.143 | 1.397 | |
| c* | Thin lead | 0.013 | 0.018 | 0.330 | 0.457 | |
| C | Thick lead | 0.023 | 0.028 | 0.584 | 0.711 | |
| c1 | Thin lead | 0.013 | 0.017 | 0.330 | 0.431 | |
| CI | Thick lead | 0.023 | 0.027 | 0.584 | 0.685 | |
| | c2 | 0.045 | 0.055 | 1.143 | 1.397 | |
| | D | 0.340 | 0.380 | 8.636 | 9.652 | |
| | D1 | 0.220 | 0.240 | 5.588 | 6.096 | |
| | D2 | 0.038 | 0.042 | 0.965 | 1.067 | |
| | D3 | 0.045 | 0.055 | 1.143 | 1.397 | |
| | D4 | 0.044 | 0.052 | 1.118 | 1.321 | |
| | Е | 0.380 | 0.410 | 9.652 | 10.414 | |
| | E1 | 0.245 | - | 6.223 | = | |
| E2 | | 0.355 | 0.375 | 9.017 | 9.525 | |
| | E3 | 0.072 | 0.078 | 1.829 | 1.981 | |
| е | | 0.100 |) BSC | 2.54 BSC | | |
| K | | 0.045 | 0.055 | 1.143 | 1.397 | |
| L | | 0.575 | 0.625 | 14.605 | 15.875 | |
| L1 | | 0.090 | 0.110 | 2.286 | 2.794 | |
| L2 | | 0.040 | 0.055 | 1.016 | 1.397 | |
| L3 | | 0.050 | 0.070 | 1.270 | 1.778 | |
| L4 | | 0.010 BSC | | 0.254 BSC | | |
| | М | - | 0.002 | - | 0.050 | |
| ECN: T13-0707-Rev. K, 30-Sep-13 | | | | | | |

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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